## 1. (total 20 points: 10 points, 10 points)

Consider a power MOSFET for which the thermal resistance parameters are:

 $\begin{aligned} \theta_{\text{dev-case}} &= 1.75\,^{\circ}\text{C/W} & \theta_{\text{case-snk}} &= 1\,^{\circ}\text{C/W} \\ \theta_{\text{snk-amb}} &= 5\,^{\circ}\text{C/W} & \theta_{\text{case-amb}} &= 50\,^{\circ}\text{C/W} \end{aligned}$ 

The ambient temperature is  $T_{amb} = 30 \text{ °C}$ , and the maximum junction or device temperature is  $T_{j,max} = T_{dev} = 150 \text{ °C}$ .

(a) Determine the maximum power dissipation in a transistor, with and without the heat sink.

(b) With sink, determine the temperature of the transistor case and the heat sink.

### 2. (total 10 points: 10 points)

Derive the relationship between  $i_{Cn}$  and  $i_{Cp}$  in the following figure, assuming the quiescent collector current is  $I_{CO}$ .



### 3. (total 20 points: 10 points, 10 points)

Consider the class-A emitter-follower circuit shown in Figure P8.16. Assume all transistors are matched with  $V_{BE}(\text{on}) = 0.7 \text{ V}$ ,  $V_{CE}(\text{sat}) = 0.2 \text{ V}$ , and  $V_A = \infty$ . Neglect base currents. Determine the maximum and minimum values of output voltage and the corresponding input voltages for the circuit to operate in the linear region.

### 4. (total 10 points: 10 points)

Find the relationship between  $v_0$  and  $v_{11} - v_{12}$  in Figure 9.26.



Figure 9.26 Instrumentation amplifier

Figure 9.42 Op-amp voltage reference circuit

# 5. (total 10 points: 5 points, 5 points)

In Figure 9.42, D1 is a diode with cut-in voltage 0.7V and the Zener diode breakdown voltage is

 $V_Z$ . Find the output voltage  $v_O$  and  $I_F$ , assuming  $\frac{R_4}{R_3 + R_4} V_S > V_Z + 0.7$ .

#### 6. (total 20 points: 20 points)

Show that the output resistance in Figure P9.59 is given by

$$R_o = \frac{R_1 R_2 R_3}{R_1 R_3 - R_2 R_F}$$



Figure P9.59

## 7. (total 10 points: 10 points)

Find the output  $v_0$  in terms of  $v_{I1}$  and  $v_{I2}$ .

